L Number	Hits		DB	Time stamp
_	4841	((438/30) or (438/128) or (438/149) or (438/488) or (438/489) or (438/491) or	USPAT; US-PGPUB;	2004/01/11 22:17
	i	(438/795)).CCLS.	EPO; JPO; DERWENT; IBM TDB	
-	0	quasi near2 strip near2 like near2 crystal	USPAT; US-PGPUB;	2004/01/11 22:35
			EPO; JPO; DERWENT; IBM TDB	
_	2	quasi near2 strip near2 like	USPAT; US-PGPUB;	2004/01/11 21:24
			EPO; JPO; DERWENT; IBM_TDB	
-	1188	polycrystalline same recrystallization	USPAT; US-PGPUB; EPO; JPO;	2004/01/11 21:25
	0	////29/20\ or //29/129\ or //29/140\ or	DERWENT; IBM_TDB	2004/01/11 21 25
		(438/488) or (438/489) or (438/491) or (438/795)).CCLS.) and (quasi near2 strip	USPAT; US-PGPUB; EPO; JPO;	2004/01/11 21:25
_	7080	near2 like ) reformation	DERWENT; IBM_TDB USPAT;	2004/01/11 21:25
		10202.110020.1	US-PGPUB; EPO; JPO;	2004/01/11 21.23
-	83908	polycrystalline	DERWENT; IBM_TDB USPAT;	2004/01/11 22:21
			US-PGPUB; EPO; JPO; DERWENT;	
_	6	reformation same polycrystalline	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/01/11 21:27
-	84120	F 1 1   F	DERWENT; IBM_TDB USPAT;	2004/01/11 22:30
		film))	US-PGPUB; EPO; JPO; DERWENT;	I i
-	156387	anneal or annealing	IBM_TDB USPAT; US-PGPUB;	2004/01/11 21:29
			EPO; JPO; DERWENT; IBM TDB	
-	5374	<pre>(polycrystalline or (p adj si adj (layer or film)) ) same (anneal or annealing)</pre>	USPAT; US-PGPUB; EPO; JPO;	2004/01/11 21:29
-	681508	laser	DERWENT; IBM_TDB USPAT;	2004/01/11 21:29
			US-PGPUB; EPO; JPO; DERWENT;	
-	1662	laser same ((polycrystalline or (p adj si adj (layer or film)) ) same (anneal or	IBM_TDB USPAT; US-PGPUB;	2004/01/11 21:30
		annealing))	EPO; JPO; DERWENT;	
-	2666	lateral near2 growth	IBM_TDB USPAT; US-PGPUB;	2004/01/11 21:30
			EPO; JPO; DERWENT; IBM TDB	

-	23	adj (layer or film)) ) same (anneal or	USPAT; US-PGPUB;	2004/01/11 21:30
		annealing))) same (lateral near2 growth)	EPO; JPO; DERWENT;	
_	5	(("200243222") or ("2002100637")).PN.	IBM_TDB USPAT;	2004/01/11 21:39
			US-PGPUB; EPO; JPO;	,
			DERWENT;	
_	202391	irradiate or irradiating	<pre>IBM_TDB USPAT;</pre>	2004/01/11 21:42
			US-PGPUB; EPO; JPO;	
			DERWENT;	
_	89	(irradiate or irradiating) near	IBM_TDB USPAT;	2004/01/11 22:21
		(polycrystalline or (p adj si adj (layer or film)))	US-PGPUB; EPO; JPO;	
			DERWENT;	
-	5342	1 ' ' ' ' ' ' ' ' ' ' ' ' ' ' ' ' ' ' '	IBM_TDB USPAT;	2004/01/11 22:17
		(438/166) or (438/488) or (438/489) or (438/491) or (438/795)).CCLS.	US-PGPUB; EPO; JPO;	
			DERWENT;	
_	26893	reform or reformation	<pre>IBM_TDB USPAT;</pre>	2004/01/11 22:19
			US-PGPUB; EPO; JPO;	
			DERWENT;	
-	0	((irradiate or irradiating) near	IBM_TDB USPAT;	2004/01/11 22:19
		<pre>(polycrystalline or (p adj si adj (layer or film)) )) same (reform or reformation)</pre>	US-PGPUB; EPO; JPO;	:
			DERWENT; IBM TDB	
_	0	((irradiate or irradiating) near	USPAT;	2004/01/11 22:19
		<pre>(polycrystalline or (p adj si adj (layer or film)) )) and (reform or reformation)</pre>	US-PGPUB; EPO; JPO;	
			DERWENT; IBM_TDB	
-	25571	pulse near laser	USPAT;	2004/01/11 22:21
	į		US-PGPUB; EPO; JPO;	
			DERWENT; IBM TDB	
-	369	<pre>(pulse near laser) same (polycrystalline or (p adj si adj (layer or film)) )</pre>	USPAT; US-PGPUB;	2004/01/11 22:22
			EPO; JPO;	
			DERWENT; IBM_TDB	
_	177	((pulse near laser) same (polycrystalline or (p adj si adj (layer or film)) )) and	USPAT; US-PGPUB;	2004/01/11 22:22
		(irradiate or irradiating)	EPO; JPO; DERWENT;	
_	41017	(polygraphalling on (p. 144 -41) c. (7	IBM_TDB	
=	41017	<pre>(polycrystalline or (p adj si)) near2 (layer or film)</pre>	USPAT; US-PGPUB;	2004/01/11 22:42
			EPO; JPO; DERWENT;	
-	41	selective near irradiating	IBM_TDB USPAT;	2004/01/11 02 24
			US-PGPUB;	2004/01/11 22:34
			EPO; JPO; DERWENT;	
_	1	((polycrystalline or (p adj si)) near2	IBM_TDB USPAT;	2004/01/11 22:32
		(layer or film) ) and (selective near irradiating)	US-PGPUB;	2001/01/11 22:32
		TITAGIACING)	EPO; JPO; DERWENT;	
			IBM_TDB	

[-	17	(irradiate or irradiating) near (selective	USPAT;	2004/01/11 22:35
		near irradiating)	US-PGPUB;	
			EPO; JPO;	
: 			DERWENT;	
			IBM TDB	1
_	103	quasi near like	USPAT;	2004/01/11 22:35
		44442	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	0	((irradiate or irradiating) near	USPAT;	2004/01/11 22:35
		((polycrystalline or (p adj si)) near2	US-PGPUB;	
		(layer or film) )) and (quasi near like)	EPO; JPO;	
ţ		( <b>1</b>	DERWENT;	
			IBM TDB	
1 _	104	(irradiate or irradiating) near	USPAT;	2004/01/11 22:40
		((polycrystalline or (p adj si)) near2	US-PGPUB;	
		(layer or film)	EPO; JPO;	
		, , ,	DERWENT;	
			IBM TDB	
_	101	sequential near lateral near solidification	USPAT;	2004/01/11 22:41
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	55	(sequential near lateral near	USPAT;	2004/01/11 22:42
		solidification) and ((polycrystalline or (p	US-PGPUB;	
		adj si)) near2 (layer or film) )	EPO; JPO;	
			DERWENT;	
			IBM_TDB	